

# PDTA123YT

PNP resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ Rev. 02 — 11 June 2004 Objective data

## **Product profile**

## 1.1 General description

PNP resistor-equipped transistor. NPN complement: PDTC123YT.

#### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs.

### 1.3 Applications

- General-purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

#### 1.4 Quick reference data

Table 1: **Quick reference data** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage		-	-	-50	V
I <sub>O</sub>	output current (DC)		-	-	-100	mA
R1	bias resistor		-	2.2	-	kΩ
R2	bias resistor		-	10	-	kΩ

#### **Pinning information** 2.

Table 2. Discrete ninning

Pin	Description	Simplified outline	Symbol		
1	base				
2	emitter	[3]	3		
3	collector	1 2 SOT23	1 R1 R2 Sym003		



## 3. Ordering information

**Table 3: Ordering information** 

Type number	er Package		
	Name	Description	Version
PDTA123YT	-	plastic surface mounted package; 3 leads	SOT23

## 4. Marking

Table 4: Marking

Type number	Marking code [1]
PDTA123YT	*AD

<sup>[1] \* =</sup> p: made in Hong Kong.

## 5. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-50	V
$V_{CEO}$	collector-emitter voltage	open base	-	-50	V
$V_{EBO}$	emitter-base voltage	open collector	-	<b>-</b> 5	V
VI	input voltage				
	positive		-	+5	V
	negative		-	-12	V
Io	output current (DC)		-	-100	mA
I <sub>CM</sub>	peak collector current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> _	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

<sup>[1]</sup> Refer to standard mounting conditions.

## 6. Thermal characteristics

Table 6: Thermal characteristics

Symbol	Parameter	Conditions	Value	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> 500	K/W

<sup>[1]</sup> Refer to standard mounting conditions.

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<sup>\* =</sup> t: made in Malaysia.

<sup>\* =</sup> W: made in China.

## 7. Characteristics

**Table 7: Characteristics** 

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μΑ
	cut-off current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$	-	-	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-700	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	35	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	-	-	-150	mV
$V_{i(off)}$	input-off voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-0.75	-0.3	V
V <sub>i(on)</sub>	input-on voltage	$V_{CE} = -300 \text{ mV}; I_{C} = -20 \text{ mA}$	-2.5	-1.15	-	V
R1	input resistor		1.54	2.2	2.86	kΩ
R2/ <sub>R1</sub>	resistor ratio		3.6	4.5	5.5	
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	-	2	pF

## **Package outline**

#### Plastic surface mounted package; 3 leads

SOT23

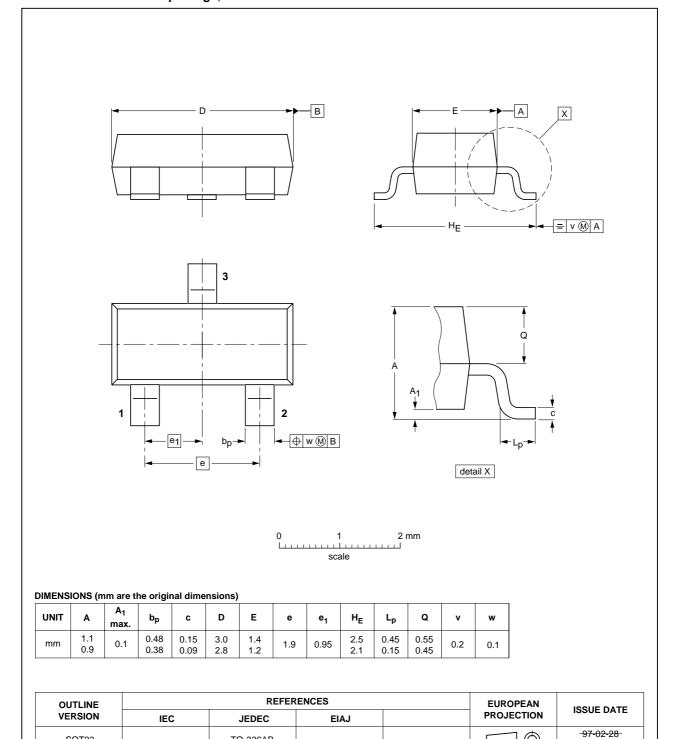


Fig 1. Package outline.

SOT23

99-09-13

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TO-236AB

## 9. Revision history

### Table 8: Revision history

Document ID	Release date	Data sheet status	Change notice	Order number	Supersedes
PDTA123YT_2	20040611	Objective data	-	9397 750 13217	PDTA123YT_1
Modifications:	<ul> <li>C<sub>c(max)</sub> = 2 pF (was <tbd>); see <u>Table 7 "Characteristics"</u></tbd></li> <li>V<sub>i(off)(typ)</sub> = -0.75 V (was <tbd>); see <u>Table 7 "Characteristics"</u></tbd></li> <li>V<sub>i(on)(typ)</sub> = -1.15 V (was <tbd>); see <u>Table 7 "Characteristics"</u></tbd></li> </ul>				
PDTA123YT_1	20040325	Objective data	-	9397 750 12549	-



Level	Data sheet status [1]	Product status [2] [3]	Definition
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